

Description : 50 Ohms Terminated SP10T 3GHz SMA LATCHING 12V SWITCH
 Options : SELF CUT-OFF / AUTO RESET / TTL DRIVE / SUPP. DIODES

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RF CHARACTERISTICS

Number of ways : 10
 Frequency range : 0 - 3 GHz
 Impedance : 50 Ohms

Frequency (GHz)	0 - 3
VSWR max	1.20
Insertion loss max	0.20 dB
Isolation min	80 dB
Average power (*)	240 W

TERMINATION IMPEDANCE : 50 Ohms
 TERM. AVG. POWER AT 25° C : 1 W per termination
 3 W total power

ELECTRICAL CHARACTERISTICS

Actuator : LATCHING
 Nominal current ** : 1280 mA
 Actuator voltage (Vcc) : 12V (10.2 to 13V) / NEGATIVE COMMON
 Terminals : solder pins (250°C max. / 30 sec.)
 Self cut-off time : 40 ms < CT < 120 ms
 TTL inputs (E) - High level : 2.2 to 5.5 V / 800µA at 5.5 V
 - Low level : 0 to 0.8 V / 20µA at 0.8 V

MECHANICAL CHARACTERISTICS

Connectors : SMA female per MIL-C 39012
 Life : 2.000.000 cycles per position
 Switching Time*** : < 50 ms
 Construction : Splashproof
 Weight : < 360 g

ENVIRONMENTAL CHARACTERISTICS

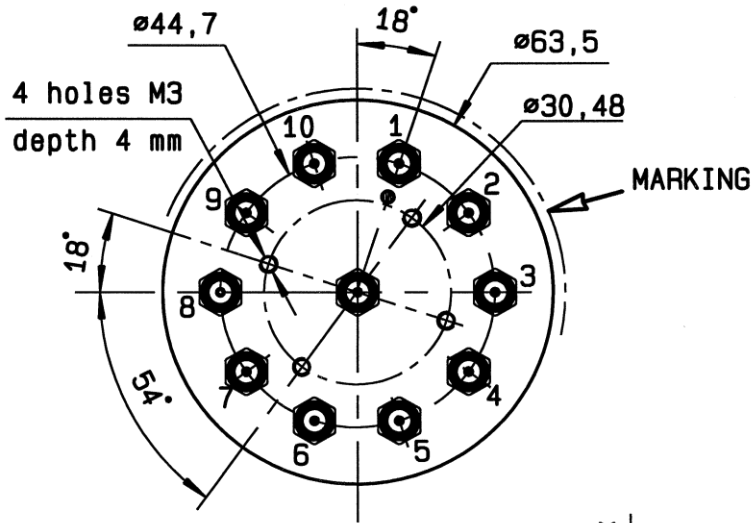
Operating temperature range : -40°C to +85°C
 Storage temperature range : -55°C to +85°C

(* Average power at 25°C per RF Path)
 (** At 25° C ±10%)
 (***) Nominal voltage ; 25° C)

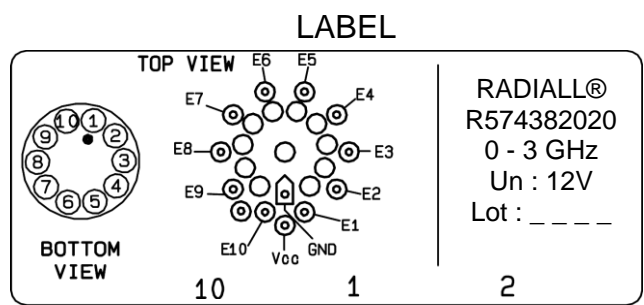
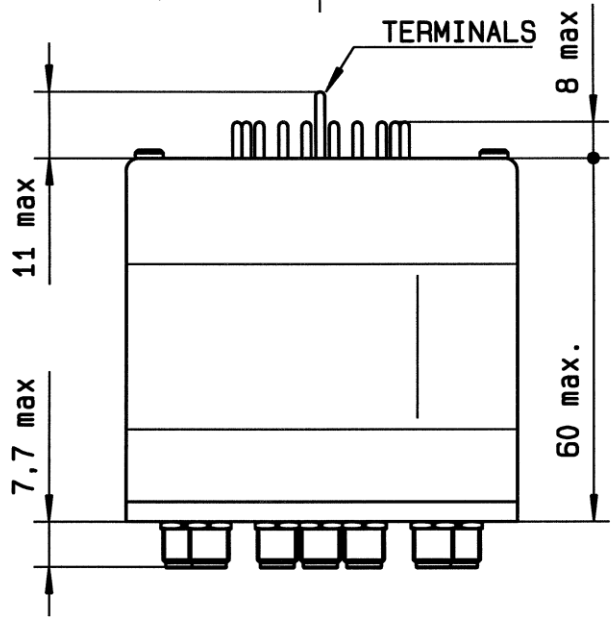


This information is given as an indication. In order to improve our products, we reserve the right to make any modifications judged necessary

DRAWING

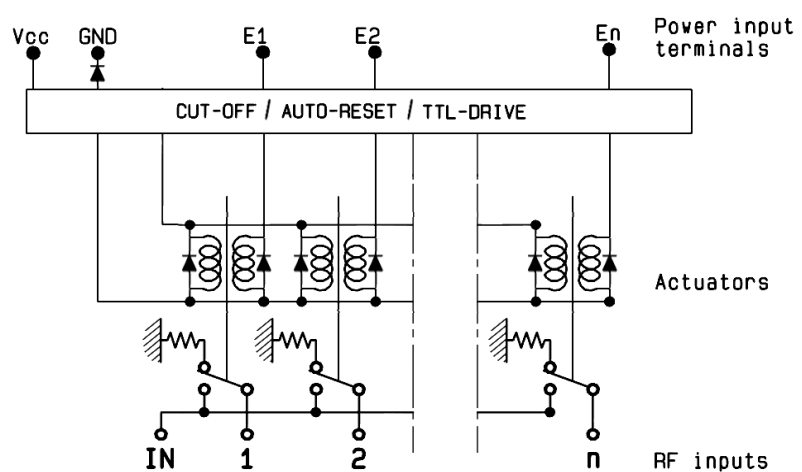


TTL input	RF Continuity
E1 = 1	IN ↔ 1
E2 = 1	IN ↔ 2
E3 = 1	IN ↔ 3
E4 = 1	IN ↔ 4
E5 = 1	IN ↔ 5
E6 = 1	IN ↔ 6
E7 = 1	IN ↔ 7
E8 = 1	IN ↔ 8
E9 = 1	IN ↔ 9
E10 = 1	IN ↔ 10



General tolerances : ±0.5 mm

SCHEMATIC DIAGRAM



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